

<b>L Number</b>	<b>Hits</b>	<b>Search Text</b>	<b>DB</b>	<b>Tim stamp</b>
1	627	display and semiconductor and (ion adj implant\$) and electrode and drain and gate and method and capacitor	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USOCR	2004/05/17 06:02
2	0	display and semiconductor and (ion adj implant\$) and electrode and drain and gate and method and capacitor	EPO; JPO; DERWENT; IBM_TDB USOCR	2004/05/17 06:02
3	3	display and semiconductor and (ion adj implant\$) and electrode and drain and gate and method and capacitor	EPO; JPO; DERWENT; IBM_TDB US-PGPUB	2004/05/17 06:02
4	624	display and semiconductor and (ion adj implant\$) and electrode and drain and gate and method and capacitor	EPO; JPO; DERWENT; IBM_TDB US-PGPUB	2004/05/17 06:02